

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	200	(termination or terminator or resistance near match\$4 or impedance near match\$3) near4 (resistor or linear or linearity) same (gate and source and drain)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/04 09:08
L2	178	(on-die) near3 (termination or matching)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/04 09:22
L4	285	(active) near (termination or terminator) and (mos or mosfet or pmos or nmos) and (resistor or resistance or impedance)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/04 09:39
L7	293	(termination or terminating or terminator or matching) near3 (resistor or resistance or impedance) and (third or three or tertiary) near3 (mos or mosfet or transistor or nmos or pmos) same resistor near6 (gate or source or drain)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/04 10:38
L8	141	(termination or terminating or terminator or matching) near3 (resistor or resistance or impedance) and (third or three or tertiary) near3 (mos or mosfet or transistor or nmos or pmos) near8 (resistor) near5 (source or gate or drain)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/04 10:58
L9	459	(impedance near matching) near10 (mos or mosfet or nmos or pmos or fet or transistor) near10 (resistor or resistance or resistive)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/04 11:09
L10	22	(odt or on-die-termination) near5 (fet or mosfet or nmos or pmos or mos)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/04 11:33
L13	421	257/363.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/04 12:05

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L15	283	257/380.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/04 12:32
L17	179	257/E27.033.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/04 12:44
L20	220	326/30,83.ccls. and (termination or terminated or terminating or (impedance or resistance) near3 (match\$4 or compensat\$4)) near8 (fet or mos or mosfet or nmos or pmos or misfet)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/04 12:46
L21	227	326/30,83.ccls. and (termination or terminated or terminating or (impedance or resistance) near3 (match\$4 or compensat\$4) or active near2 (resistor or resistance)) near8 (fet or mos or mosfet or nmos or pmos or misfet)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/04 13:20
L22	275	326/30,83.ccls. and (plural or plurality or multiple or third) near2 (fet or mos or mosfet or nmos or pmos or misfet) and resistor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/04 13:22
L23	22	257/350,363,379,380,E27.016,E27.033.ccls. and (termination or terminated or terminating or (impedance or resistance) near3 (match\$4 or compensat\$4) or active near2 (resistor or resistance)) near8 (fet or mos or mosfet or nmos or pmos or misfet)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/04 13:21
L24	187	257/350,363,379,380,E27.016,E27.033.ccls. and (plural or plurality or multiple or third) near2 (fet or mos or mosfet or nmos or pmos or misfet) and resistor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/04 13:32
L25	20	"6429685".pn. "6560290".pn. "6525558".pn. "5680060".pn. "6424169".pn. "5329190".pn. "6362655".pn. "5821768".pn. "6388495".pn. "6351138".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/04 13:45

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L27	390	(active near (resistor or resistance) or (resistance or impedance) near2 (match\$3) or termination or terminating) near6 (linear\$4) and (mos or mosfet or fet or pmos or nmos or field near effect near transistor or misfet)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/04 13:47
L28	234	(active near (resistor or resistance) or (resistance or impedance) near2 (match\$3) or termination or terminating) near6 (linear\$4) and (mos or mosfet or fet or pmos or nmos or field near effect near transistor or misfet) and (gate) and (source or drain)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/04 13:59

Interference Search

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L29	85	((termination or terminating or terminated) near3 (resistor or resistance or impedance) and (mosfet or mos or nmos or pmos or fet or field near effect near transistor or misfet)).clm.	US-PGPUB	OR	ON	2006/05/04 14:49
L30	16	((active adj resistor)).clm.	US-PGPUB	OR	ON	2006/05/04 14:55
L31	47	((active adj resistor or terminat\$3 near (resistor or impedance)) and (plural or plurality or multiple or multi or three or third) near3 (transistor or mosfet or mos or fet or nmos or pmos or misfet)).clm.	US-PGPUB	OR	ON	2006/05/04 15:02
L32	37	((on-chip or on-die) near2 termination).clm.	US-PGPUB	OR	ON	2006/05/04 15:03
L33	0	(termination near resistor and (mosfet or nmos or pmos or nmosfet or pmosfet) and (resistor) near3 (gate) and resistor near3 (source or drain or terminal)).clm.	US-PGPUB	OR	ON	2006/05/04 15:04